

LM217M LM317M

MEDIUM CURRENT 1.2 TO 37V ADJUSTABLE VOLTAGE REGULATOR

- OUTPUT VOLTAGE RANGE: 1.2 TO 37V
- OUTPUT CURRENT IN EXCESS OF 500 mA
- LINE REGULATION TYP. 0.01%
- LOAD REGULATION TYP. 0.1%
- THERMAL OVERLOAD PROTECTION
- SHORT CIRCUIT PROTECTION
- OUTPUT TRANSITION SAFE AREA COMPENSATION
- FLOATING OPERATION FOR HIGH VOLTAGE APPLICATIONS

DESCRIPTION

The LM217M/LM317M are monolithic integrated circuits in TO-220 and DPAK packages intended for use as positive adjustable voltage regulators.

They are designed to supply until 500 mA of load current with an output voltage adjustable over a 1.2 to 37V range.

The nominal output voltage is selected by means of only a resistive divider, making the device exceptionally easy to use and eliminating the stocking of many fixed regulators.



SCHEMATIC DIAGRAM



LM217M/LM317M

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{I-} V _O	Input-Output Differential Voltage	40	V	
Pd	Power Dissipation		Internally Limited	
т	Operating Junction Temperature	for LM217M	-40 to 125	°C
T _{opr}	Range (*)	for LM317M	0 to 125	
T _{stg}	Storage Temperature Range		-55 to 150	°C

(*) Re-Boot is not guaranteed for $T_J \ge 85^{\circ}C$.

THERMAL DATA

Symbol	Parameter	SOT-82 SOT-194 DPAK	TO-220	Unit	
R _{thj-case}	Thermal Resistance Junction-case Max	8	3	°C/W	
R _{thj-amb}	Thermal Resistance Junction-ambient Max	100	50	°C/W	

CONNECTION DIAGRAM (top view)



ORDERING CODES

ТҮРЕ	TO-220	DPAK (*)
LM217M	LM217MT	LM217MDT
LM317M	LM317MT	LM317MDT

(*) Available in Tape & Reel with the suffix "-TR".

TEST CIRCUIT



Symbol	Parameter	Test Conditions			Тур.	Max.	Unit
ΔV_O	Line Regulation	$V_{I} - V_{O} = 3 \text{ to } 40 \text{ V}$	T _J = 25°C		0.01	0.02	%/V
					0.02	0.05	
∆V _O Load Re	Load Regulation	$V_0 \le 5 V$	T _J = 25°C		5	15	mV
		I _O = 10 to 500mA			20	50	
		$V_{O} \ge 5 V$	T _J = 25°C		0.1	0.3	%/V ₀
		I _O = 10 to 500mA			0.3	1	
I _{ADJ}	Adjustment Pin Current				50	100	μA
ΔI_{ADJ}	Adjustment Pin Current	$V_1 - V_0 = 3 \text{ to } 40 \text{ V}$ $I_0 = 10 \text{ to } 500 \text{ mA}$			0.2	5	μA
V_{REF}	Reference Voltage	$V_{I} - V_{O} = 3 \text{ to } 40 \text{ V}$ $I_{O} = 10 \text{ to } 500 \text{ mA}$		1.2	1.25	1.3	V
$\Delta V_0 / V_0$	Output Voltage Temperature Stability				0.7		%
I _{O(min)}	Minimum Load Current	V _I - V _O = 40 V			3.5	5	mA
I _{O(max)}	Maximum Output Current	V_{I} - $V_{O} \le 15 V$		500	1000		mA
		$V_{I} - V_{O} = 40 V$, $P_{d} < P_{dMAX}$, $T_{J} = 25^{\circ}C$			200		
eN	Output Noise Voltage (percentage of V _O)	B = 10 Hz to 100 KHz $T_J = 25^{\circ}C$			0.003		%
SVR	Supply Voltage Rejection (*)	$T_J = 25^{\circ}C$	$C_{ADJ} = 0$		65		dB
		f = 120 Hz	C _{ADJ} = 10 μF	66	80		1

ELECTRICAL CHARACTERISTICS OF LM217M (refer to the test circuits, T _J = - 40 to 125°C,
$V_1 - V_0 = 5 V$, $I_0 = 100 mA$, $P_d \le 7.5 W$, unless otherwise specified).

(*) CADJ is connected between Adjust pin and Ground.

ELECTRICAL CHARACTERISTICS OF LM317M (refer to the test circuits, $T_J = 0$ to 125°C, $V_I - V_O = 5 V$, $I_O = 100 \text{ mA}$, $P_d \le 7.5 \text{ W}$, unless otherwise specified).

Symbol	Parameter	Test Conditions			Тур.	Max.	Unit
ΔV_{O}	Line Regulation	$V_{I} - V_{O} = 3 \text{ to } 40 \text{ V}$	T _J = 25°C		0.01	0.04	%/V
					0.02	0.07	
ΔV _O Loa	Load Regulation	$V_0 \le 5 V$	T _J = 25°C		5	25	mV
		I _O = 10 to 500mA			20	70	
		$V_{O} \ge 5 V$	$T_J = 25^{\circ}C$		0.1	0.5	%/V _O
		I _O = 10 to 500mA			0.3	1.5	
I _{ADJ}	Adjustment Pin Current				50	100	μΑ
ΔI_{ADJ}	Adjustment Pin Current	$V_{I} - V_{O} = 3 \text{ to } 40 \text{ V}$ $I_{O} = 10 \text{ to } 500 \text{ mA}$			0.2	5	μA
V_{REF}	Reference Voltage	$V_{I} - V_{O} = 3 \text{ to } 40 \text{ V} \ I_{O} = 10 \text{ to } 500 \text{ mA}$		1.2	1.25	1.3	V
$\Delta V_0 / V_0$	Output Voltage Temperature Stability				0.7		%
I _{O(min)}	Minimum Load Current	V _I - V _O = 40 V			3.5	10	mA
I _{O(max)}	Maximun Output Current	V_{I} - $V_{O} \le 15 V$		500	1000		mA
		$V_{I} - V_{O} = 40 V, P_{d}$	< P _{dMAX} , T _J = 25°C		200		
eN	Output Noise Voltage (percentage of V_O)	B = 10 Hz to 100 KHz $T_J = 25^{\circ}C$			0.003		%
SVR	Supply Voltage Rejection (*)	$T_J = 25^{\circ}C$	$C_{ADJ} = 0$		65		dB
		f = 120 Hz	C _{ADJ} = 10 μF	66	80		

(*) CADJ is connected between Adjust pin and Ground.

57



Figure 1 : Current Limit

Figure 2 : Minimum Operating Current

Figure 3 : Basic Adjustable Regulator







57

 P_{dmax} calculated for $T_a = 50$ °C.

APPLICATION INFORMATION

The LM217M/LM317M provide an internal reference voltage of 1.25V between the output and adjustment terminals. These devices are used to set a constant current flow across an external resistor divider (see fig. 3), giving an output voltage V_O of: $V_O = V_{REF} (1 + R_2 / R_1) + I_{ADJ} R_2$

The devices were designed to minimize the term I_{ADJ} (100µA max) and to maintain it very constant in line and load changes. Usually, the error term $I_{ADJ} \times R_2$ can be neglected. To obtain the previous requirement, all the regulator quiescent current is returned to the output terminal, imposing a minimum load current condition. If the load is insufficient, the output voltage will rise.

Since the LM217M/LM317M devices are floating regulators and "see" only the input-to-output differential voltage, supplies of very high voltage with respect to ground can be regulated as long as the maximum input-to-output differential is not exceeded. Furthermore, programmable regulators are easily obtained and, by connecting a fixed resistor between the adjustment and output, the devices can be used as a precision current regulator. In order to optimize the load regulation, the current set resistor R_1 (see fig. 3) should be tied as close as possible to the regulator, while the ground terminal of R_2 should be near the ground of the load to provide remote ground sensing.

EXTERNAL CAPACITORS (Fig.5)

Normally no capacitors are needed unless the devices are situated far from the input filter capacitors; in which case an input bypass is needed.

A 0.1μ F disc or 1μ F tantalum input bypass capacitor (C_I) is recommended to reduce the sensitivity to input line impedance.

The adjustment terminal may be bypassed to ground to improve ripple rejection. This capacitor (Cadj) prevents ripple from being amplified as the output voltage is increased. A 10μ F capacitor should improve ripple rejection of about 80dB at 120Hz in a 10V application.

Although the LM217M/LM317M devices are stable with no output capacitance like any feedback circuit, certain values of external capacitance can cause excessive ringing. An output capacitance (C_0) in the form of a 1µF tantalum or 25µF aluminium electrolytic capacitor on the output swamps this effect and insures stability.

PROTECTION DIODES (Fig.5)

When external capacitors are used with any IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator.

Figure 5 shows the LM217M/LM317M with the recommended protection diodes for output voltages in excess of 25V or high capacitance values ($C_3 > 25\mu$ F, $C_2 > 10\mu$ F). Diode D1 prevents C_3 from discharging through the IC during an input short-circuit. The combination of diodes D1 and D2 prevents C_2 from discharging through the regulator during an input or output short-circuit.

START-UP BLOCK

It's not guaranteed the Re-Boot of the device when the junction temperature is over 85°C.

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LM217M/LM317M





Figure 6 : Slow Turn-on 15V Regulator



Figure 7 : Current Regulator



57

Figure 8 : 5V Electronic Shut-down Regulator



Figure 9 : Digitally Selected Outputs



LM217M/LM317M

DIM.		mm.		inch			
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А	4.40		4.60	0.173		0.181	
С	1.23		1.32	0.048		0.051	
D	2.40		2.72	0.094		0.107	
D1		1.27			0.050		
Е	0.49		0.70	0.019		0.027	
F	0.61		0.88	0.024		0.034	
F1	1.14		1.70	0.044		0.067	
F2	1.14		1.70	0.044		0.067	
G	4.95		5.15	0.194		0.203	
G1	2.4		2.7	0.094		0.106	
H2	10.0		10.40	0.393		0.409	
L2		16.4			0.645		
L4	13.0		14.0	0.511		0.551	
L5	2.65		2.95	0.104		0.116	
L6	15.25		15.75	0.600		0.620	
L7	6.2		6.6	0.244		0.260	
L9	3.5		3.93	0.137		0.154	
DIA.	3.75		3.85	0.147		0.151	





8/11

DIM		mm.				
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.9	0.025		0.035
B2	5.2		5.4	0.204		0.212
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
D1		5.1			0.200	
Е	6.4		6.6	0.252		0.260
E1		4.7			0.185	
е		2.28			0.090	
e1	4.4		4.6	0.173		0.181
Н	9.35		10.1	0.368		0.397
L		1			0.039	
(L1)		2.8			0.110	
L2		0.8			0.031	
L4	0.6		1	0.023		0.039





9/11

		mm.			inch	
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
Ν	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Ро	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319





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